

September 2007

MPS8598 PNP General Purpose Amplifier

- · This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA.
- · Sourced from Process 68.



1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	60	V	
V _{CEO}	Collector-Emitter Voltage	60	V	
V _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current (DC)	100	mA	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES

Thermal Characteristics $T_a=25$ °C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

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^{1.} These ratings are based on a maximum junction temperature of 150 degrees ${\rm C.}$

^{2.} These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Voltage	I _C = 100μA	60			V
BV _{CEO}	Collector-Emitter Voltage	I _C = 10mA	60			V
BV _{EBO}	Emitter-Base Voltage	$I_E = 10\mu A$	5			V
I _{CBO}	Collector-Base Cut-off Current	V _{CB} = 60V			0.1	μΑ
I _{CEO}	Collector-Emitter Cut-off Current	V _{CB} = 60V			0.1	μΑ
I _{EBO}	Emitter-Base Cut-off Current	V _{EB} = 4V			0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 5V, I_{C} = 1.0mA$ $V_{CE} = 5V, I_{C} = 10mA$ $V_{CE} = 5V, I_{C} = 100mA$	100 100 75		300	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$ $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$			0.4 0.3	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5V$, $I_{C} = 1mA$	0.5		0.7	V
C _{ob}	Output Capacitance	V _{CB} = 5V, f = 1MHz			8	рF
C _{ib}	Input Capacitance	V _{EB} = 0.5V, f = 1MHz			30	pF
f _T	Current gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 10mA, f = 100MHz$	150		MHz	

- NOTES:

 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

 3. These ratings are based on a maximum junction temperature of 150degrees C.





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